

# BAT54CV

# Two Schottky barrier double diodes Rev. 3 — 15 November 2010

**Product data sheet** 

## **Product profile**

## 1.1 General description

Two planar Schottky barrier double diodes with common cathodes and an integrated guard ring for stress protection encapsulated in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified
- Ultra small and flat lead SMD plastic package
- Excellent coplanarity and improved thermal behavior

## 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Reverse polarity protection

#### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol         | Parameter       | Conditions             | Min        | Тур | Max | Unit |
|----------------|-----------------|------------------------|------------|-----|-----|------|
| Per diode      |                 |                        |            |     |     |      |
| l <sub>F</sub> | forward current |                        | -          | -   | 200 | mA   |
| $V_R$          | reverse voltage |                        | -          | -   | 30  | V    |
| V <sub>F</sub> | forward voltage |                        | <u>[1]</u> |     |     |      |
|                |                 | $I_F = 0.1 \text{ mA}$ | -          | -   | 240 | mV   |
|                |                 | I <sub>F</sub> = 1 mA  | -          | -   | 320 | mV   |
|                |                 | I <sub>F</sub> = 10 mA | -          | -   | 400 | mV   |
|                |                 | $I_F = 30 \text{ mA}$  | -          | -   | 500 | mV   |
|                |                 | $I_F = 100 \text{ mA}$ | -          | -   | 800 | mV   |

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



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# 2. Pinning information

Table 2. Pinning

| 10010 21 | 9                           |                    |                 |
|----------|-----------------------------|--------------------|-----------------|
| Pin      | Description                 | Simplified outline | Graphic symbol  |
| 1        | anode (diode 1)             |                    |                 |
| 2        | anode (diode 2)             | 6 5 4              | 6 5 4           |
| 3        | common cathode (diode 3, 4) |                    |                 |
| 4        | anode (diode 3)             |                    |                 |
| 5        | anode (diode 4)             |                    |                 |
| 6        | common cathode (diode 1, 2) | 1 2 3              | 1 2 3<br>sym057 |

# 3. Ordering information

Table 3. Ordering information

| Type number | Package  |  |         |
|-------------|----------|--|---------|
|             | Name     | Description                              | Version |
| BAT54CV     | <b>-</b> | plastic surface-mounted package; 6 leads | SOT666  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BAT54CV     | C5           |

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                           | Conditions                                 | Min   | Max  | Unit |
|------------------|-------------------------------------|--|-------|------|------|
| Per diode        |                                     |  |       |      |      |
| V <sub>R</sub>   | reverse voltage                     |  | -     | 30   | V    |
| I <sub>F</sub>   | forward current                     |  | -     | 200  | mA   |
| I <sub>FRM</sub> | repetitive peak forward current     | $t_p \leq 10 \text{ ms; } \delta \leq 0.5$ | -     | 0.85 | Α    |
| I <sub>FSM</sub> | non-repetitive peak forward current | square wave;<br>t <sub>p</sub> = 8.3 ms    | [1] _ | 2    | Α    |

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Table 5. Limiting values ...continued
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions                  | Min        | Max  | Unit |
|------------------|-------------------------|-----------------------------|------------|------|------|
| Per device       | e, one diode loaded     |                             |            |      |      |
| P <sub>tot</sub> | total power dissipation | $T_{amb} \le 25  ^{\circ}C$ | <u>[2]</u> |      |      |
|                  |                         |                             | [3] _      | 350  | mW   |
|                  |                         |                             | [4] _      | 420  | mW   |
| T <sub>j</sub>   | junction temperature    |                             | -          | 125  | °C   |
| T <sub>amb</sub> | ambient temperature     |                             | -65        | +125 | °C   |
| T <sub>stg</sub> | storage temperature     |                             | -65        | +150 | °C   |

<sup>[1]</sup>  $T_i = 25$  °C prior to surge.

#### 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter  | Conditions  | Min          | Тур | Max | Unit |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Per device            | , one diode loaded                               |             |              |     |     |      |
| · -ti (j-a)           | thermal resistance from junction to ambient      | in free air | [1][2]       |     |     |      |
|                       |  |             | [3]          | -   | 360 | K/W  |
|                       |  |             | [4] _        | -   | 300 | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | <u>[5]</u> _ | -   | 175 | K/W  |

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[4]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[5]</sup> Soldering point of cathode tab.

#### Two Schottky barrier double diodes

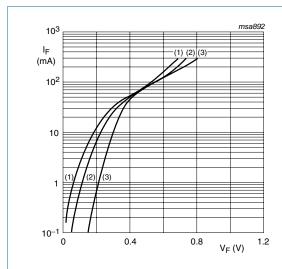
## 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

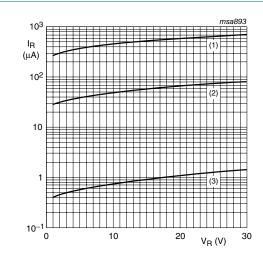
| · arrib — = 0  | C dimoco otinoi mico o | e amose carerines openios. |            |     |     |      |
|----------------|------------------------|----------------------------|------------|-----|-----|------|
| Symbol         | Parameter              | Conditions                 | Min        | Тур | Max | Unit |
| Per diode      | •                      |                            |            |     |     |      |
| V <sub>F</sub> | forward voltage        |                            | <u>[1]</u> |     |     |      |
|                |                        | $I_F = 0.1 \text{ mA}$     | -          | -   | 240 | mV   |
|                |                        | $I_F = 1 \text{ mA}$       | -          | -   | 320 | mV   |
|                |                        | $I_F = 10 \text{ mA}$      | -          | -   | 400 | mV   |
|                |                        | $I_F = 30 \text{ mA}$      | -          | -   | 500 | mV   |
|                |                        | $I_F = 100 \text{ mA}$     | -          | -   | 800 | mV   |
| I <sub>R</sub> | reverse current        | V <sub>R</sub> = 25 V      | -          | -   | 2   | μΑ   |
| C <sub>d</sub> | diode capacitance      | $V_R = 1 V$ ; $f = 1 MHz$  | -          | -   | 10  | pF   |
|                |                        |                            |            |     |     |      |

[1] Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



- (1) T<sub>amb</sub> = 125 °C
- (2) T<sub>amb</sub> = 85 °C
- (3) T<sub>amb</sub> = 25 °C

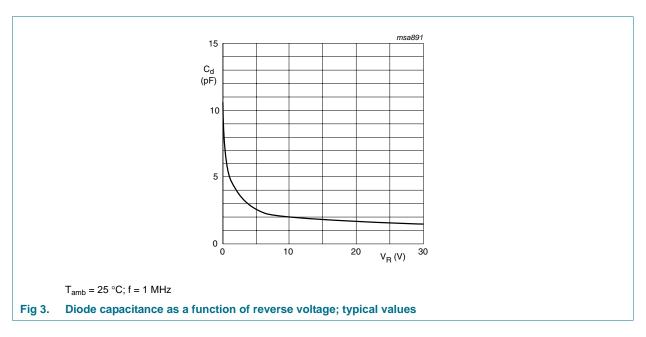
Fig 1. Forward current as a function of forward voltage; typical values



- (1) T<sub>amb</sub> = 125 °C
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

Two Schottky barrier double diodes

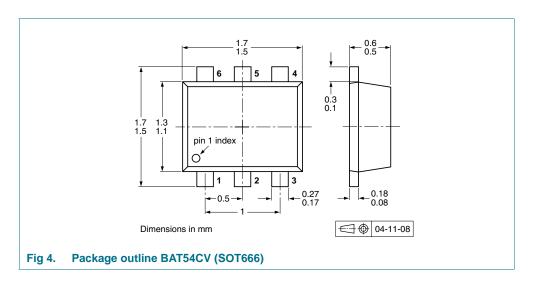


#### 8. Test information

## 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



BAT54CV

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## Two Schottky barrier double diodes

# 10. Packing information

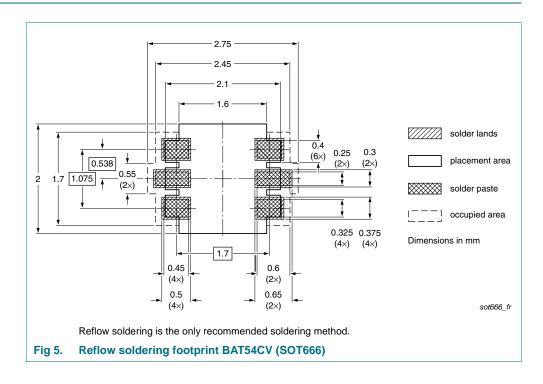
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                    | Packing quantity |
|-------------|---------|--------------------------------|------------------|
|             |         |                                | 4000             |
| BAT54CV     | SOT666  | 4 mm pitch, 8 mm tape and reel | -115             |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

# 11. Soldering



## Two Schottky barrier double diodes

# 12. Revision history

Table 9. Revision history

| Document ID    | Release date   | Data sheet status                    | Change notice | Supersedes |
|----------------|--|--------------------------------------|---------------|------------|
| BAT54CV v.3    | 20101115   | Product data sheet                   | -             | BAT54CV_2  |
| Modifications: | Section 1.2 "Fe  | atures and benefits": amer           | nded.         |            |
|                | Table 1 "Quick   | reference data": updated.            |               |            |
|                | <ul> <li>Table 5 "Limitin</li> </ul>   | g values": P <sub>tot</sub> amended. |               |            |
|                | <ul> <li><u>Table 6 "Thermal characteristics"</u>: R<sub>th(j-a)</sub> amended, R<sub>th(j-sp)</sub> added.</li> </ul> |                                      |               |            |
|                | <ul> <li>Figure 4: superseded by minimized outline drawing.</li> </ul>   |                                      |               |            |
|                | <ul> <li>Section 8 "Test information": added.</li> </ul>   |                                      |               |            |
|                | Section 11 "Soldering": added.   |                                      |               |            |
|                | <ul> <li>Section 13 "Leg</li> </ul>  | gal information": updated.           |               |            |
| BAT54CV_2      | 20100115   | Objective data sheet                 | -             | BAT54CV_1  |
| BAT54CV_1      | 20040922   | Objective data sheet                 | -             | -          |

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## 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### Two Schottky barrier double diodes

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